

# Semiconductor devices — Discrete devices —

## Part 9: Insulated-gate bipolar transistors (IGBTs)

ICS 31.080.30

## National foreword

This British Standard is the UK implementation of IEC 60747-9:2007. It supersedes BS IEC 60747-9:1998 which is withdrawn.

The UK participation in its preparation was entrusted to Technical Committee EPL/47, Semiconductors.

A list of organizations represented on this committee can be obtained on request to its secretary.

This publication does not purport to include all the necessary provisions of a contract. Users are responsible for its correct application.

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